





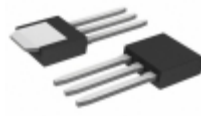
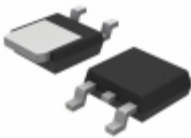
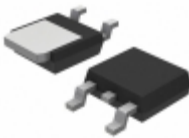
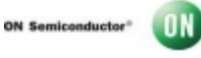
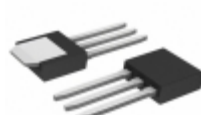
	<h2>NTD3808NT4G</h2>
	<p>Manufacturer Part Number: NTD3808NT4G</p> <p>Manufacturer/Brand: AMI Semiconductor / ON Semiconductor</p> <p>Part of Description: MOSFET N-CH 16V 12A DPAK</p> <p>Datasheets:  NTD3808NT4G.pdf</p> <p>RoHs Status:  Lead free / RoHS Compliant</p> <p>Stock Condition: New original, 10000 pcs Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	NTD3808NT4G
Manufacturer	AMI Semiconductor / ON Semiconductor
Description	MOSFET N-CH 16V 12A DPAK
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	10000 pcs Stock
Series	-
Technology	MOSFET (Metal Oxide)
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device Package	DPAK
Power Dissipation (Max)	1.3W (Ta), 52W (Tc)
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	16V
Current - Continuous Drain (Id) @ 25°C	12A (Ta), 76A (Tc)
Rds On (Max) @ Id, Vgs	5.8 mOhm @ 15A, 10V
Vgs(th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	21nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	1660pF @ 12V
Packaging	Tape & Reel (TR)







NTD3808NT4G is New Original in Stock, Search NTD3808NT4G Datasheets, PDF, Inventory at Y-IC.com Online, Order NTD3808NT4G AMI Semiconductor / ON Semiconductor with warrantied and confidence. RFQ NTD3808NT4G : Info@Y-IC.com

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 NTD40N03RG	 NTD40N03RT4	 NTD40N03RT4G	 NTD4302-001	 NTD4302-001G
 NTD4302-1G	 NTD4302G	 NTD4302T4	 NTD4302T4G	 NTD4804N
 NTD4804NT4G	 NTD4805N	 NTD4805N-1G	 NTD4805NT4G	 NTD4806N
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